

Peak Emission Wavelength: 860nm

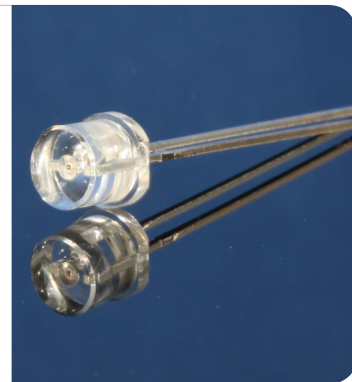
The MTE8600N2 consists of a 860nm high output infrared die in a water-clear 5mm flat top plastic molded package. Custom package solutions and sorting are available.

FEATURES

- > High Output Power
- > Wide Beam Angle
- > High Reliability

APPLICATIONS

- > Optical Switches & Sensors
- > Fiber Optical Communication



Absolute Maximum Ratings (Ta=25°C)



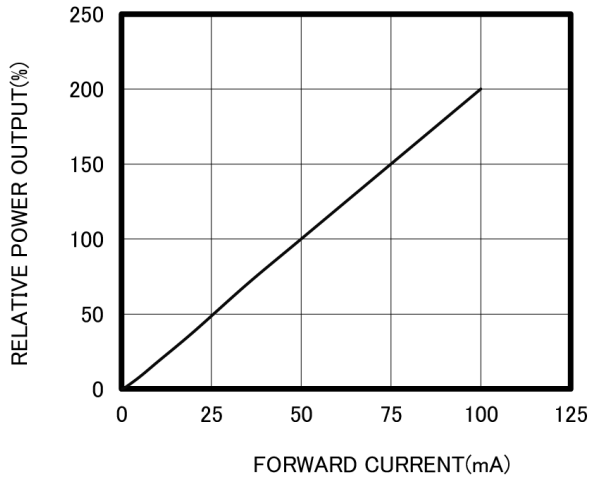
ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	1	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	190	mW
Operating Temperature Range	Topr	-20 ~ +80	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C
Junction Temperature	Tj	100	°C
Lead Soldering Temperature*2	Tls	260	°C

*1: Tw=10μsec, T=10msec. *2: Time 5Sec max, Position: Up to 3mm from the body.

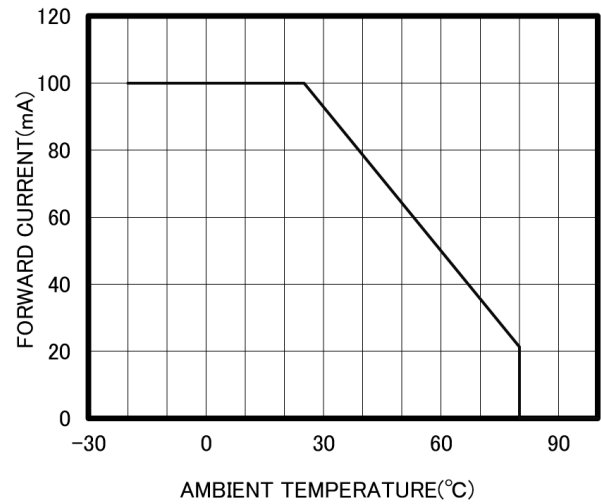
Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	--	18.0	--	mW
Forward Voltage	VF	IF=50mA	--	1.45	1.9	V
Reverse Current	IR	VR=5V	--	--	100	μA
Peak Emission Wavelength	λp	IF=50mA	--	850	--	nm
Spectral Line Half Width	Δλ	IF=50mA	--	30	--	nm
Half Intensity Beam Angle	Θ	IF=50mA	--	±55	--	deg
Switching Times	Tr, Tf	IF=50mA	--	150, 100	--	ns

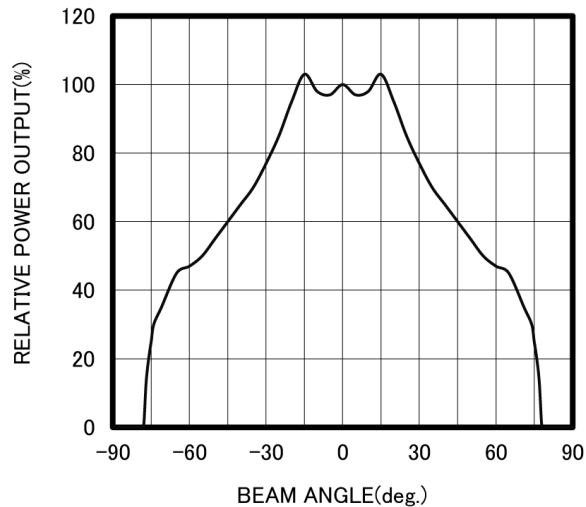
RELATIVE POWER vs FORWARD CURRENT



THERMAL DERATING CURVE



RADIATION PATTERN



The information contained herein is subject to change without notice.

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